EAST Search History

EAST Search History (Prior Art)

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	138	"6284393"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/07/30 10:47
S2	4	"2003085652"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/07/30 10:48
S3	3	"20030085652"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/07/30 10:48
S4	3	"20050007014"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/07/30 10:49
S5	5	"2004044998"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/07/30 10:49
S6	2	"20030127971"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/07/30 10:49
S7	6	"2004004421"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/07/30 10:49
S8	118	313/504.ccls. and (optical adj2 interference)	US-PGPUB; USPAT; USOCR	OR	OFF	2008/07/30 11:38

S9	8	313/504.ccls. and (optical adj2 interference) and (constructive with interference)	US-PGPUB; USPAT; USOCR	OR	OFF	2008/07/30 11:41
S10	16	(optical adj2 interference) and (constructive with interference)	FPRS; EPO; JPO; DERWENT	OR	OFF	2008/07/30 11:49
S11	0	313/504.ccls. and (bandgap with semiconductor with (light optic$2 reflect$3 spacer) with (zinc selenide gallium nitride))	US-PGPUB; USPAT; USOCR	OR	OFF	2008/07/31 09:48
S12	0	313/504.ccls. and (band $gap with semiconductor with (light optic$2 reflect $3 spacer) with (zinc selenide gallium nitride))	US-PGPUB; USPAT; USOCR	OR	OFF	2008/07/31 09:48
S13	3	313/504.ccls. and (band $gap same semiconductor same (light optic$2 reflect $3 spacer) same (zinc selenide gallium nitride))	US-PGPUB; USPAT; USOCR	OR	OFF	2008/07/31 09:49
S14	2832	313/504.ccls. and wavelength	US-PGPUB; USPAT; USOCR	OR	OFF	2008/07/31 10:05
S15	1417	313/504.ccls. and wavelength and (electron adj1 transport)	US-PGPUB; USPAT; USOCR	OR	OFF	2008/07/31 10:06
S16	775	313/504.ccls. and wavelength and (electron adj1 transport) and (cathode with transparent)	US-PGPUB; USPAT; USOCR	OR	OFF	2008/07/31 10:06
S17	252	313/504.ccls. and wavelength and (electron adj1 transport) and (cathode near1 transparent)	US-PGPUB; USPAT; USOCR	OR	OFF	2008/07/31 10:08
S18	454	"optical interference" and ("zinc selenide" ZnSe "gallium nitride" GaN)\	US-PGPUB; USPAT; USOCR	OR	OFF	2008/07/31 10:13
S19	454	"optical interference" and ("zinc selenide" ZnSe "gallium nitride" GaN)	US-PGPUB; USPAT; USOCR	OR	OFF	2008/07/31 10:14
S20	169	("OLED".U/C. display) and "optical interference" and ("zinc selenide" ZnSe "gallium nitride" GaN)	US-PGPUB; USPAT; USOCR	OR	OFF	2008/07/31 10:14
S21	2	"20030234609"	US-PGPUB; USPAT	OR	OFF	2008/07/31 11:59

S22	1363	313/504.ccls. and (cathode and (multi$layer layer optical)).ab.	US-PGPUB; USPAT; USOCR	OR	OFF	2009/10/27 14:02
S23	603	313/504.ccls. and (cathode near2 (multi $layer layer optical)).ab.	US-PGPUB; USPAT; USOCR	OR	ON	2009/10/27 14:02
S24	2	313/504.ccls. and (cathode near2 (multi $layer layer optical)).ab. and (wavelength near5 emission near10 (stack interference optical))	US-PGPUB; USPAT; USOCR	OR	ON	2009/10/27 14:03
S25	183	313/504.ccls. and (cathode near2 (multi $layer layer optical)).ab. and (wavelength near5 emission)	US-PGPUB; USPAT; USOCR	OR	ON	2009/10/27 14:04
S26	85	313/504.ccls. and ((multi $layer layer optical) near1 cathode).ab. and (wavelength near5 emission)	US-PGPUB; USPAT; USOCR	OR	ON	2009/10/27 14:05
S27	1521	313/504.ccls. and (multi $layernear1 cathode).ab.	US-PGPUB; USPAT; USOCR	OR	ON	2009/10/27 14:08
S28	1	313/504.ccls. and (multi $layer near1 cathode).ab.	US-PGPUB; USPAT; USOCR	OR	ON	2009/10/27 14:08
S29	40	313/504.ccls. and (multi $layer near1 cathode)	US-PGPUB; USPAT; USOCR	OR	ON	2009/10/27 14:09
S30	8	313/504.ccls. and (multi $layer near1 cathode) and (cathode near10 optical)	US-PGPUB; USPAT; USOCR	OR	ON	2009/10/27 14:10
S31	0	("2007/0285003").URPN.	USPAT	OR	OFF	2009/10/27 14:13

EAST Search History (Interference)

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	0	313/504.ccls. and (bandgap with semiconductor with (light optic$2 reflect$3 spacer) with (zinc selenide gallium nitride))	USPAT; UPAD	OR	OFF	2010/09/24 09:11
L2	16	313/504.ccls. and (multi $layer near1 cathode)	USPAT; UPAD	OR	ON	2010/09/24 09:11

9/24/2010 9:12:14 AM

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